

/ Descriptions

SOT23-6 P MOS
P- CHANNEL MOSFET in a SOT23-6 Plastic Package.

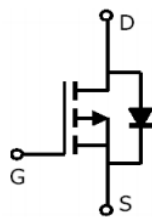
/ Features

AEC-Q101
Ultra Low on-resistance. fast switching.Low on voltage, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

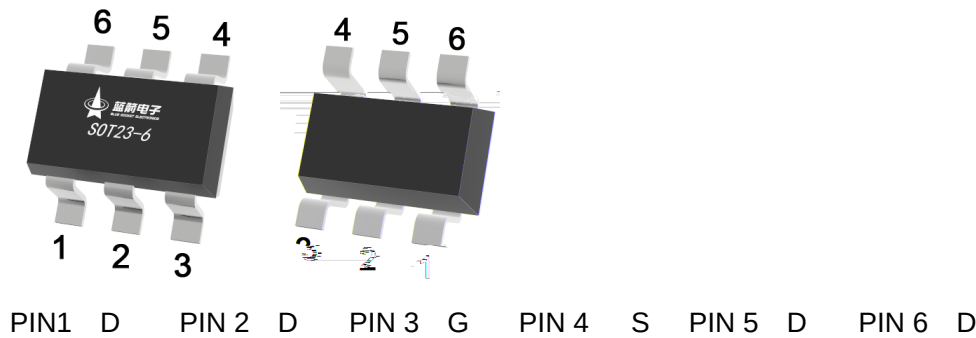
/ Applications

PWM
PWM application & Load switch, Meet the stringent requirements of automotive applications.

/ Equivalent Circuit



/ Pinning



/ Marking

Marking

Q5P06

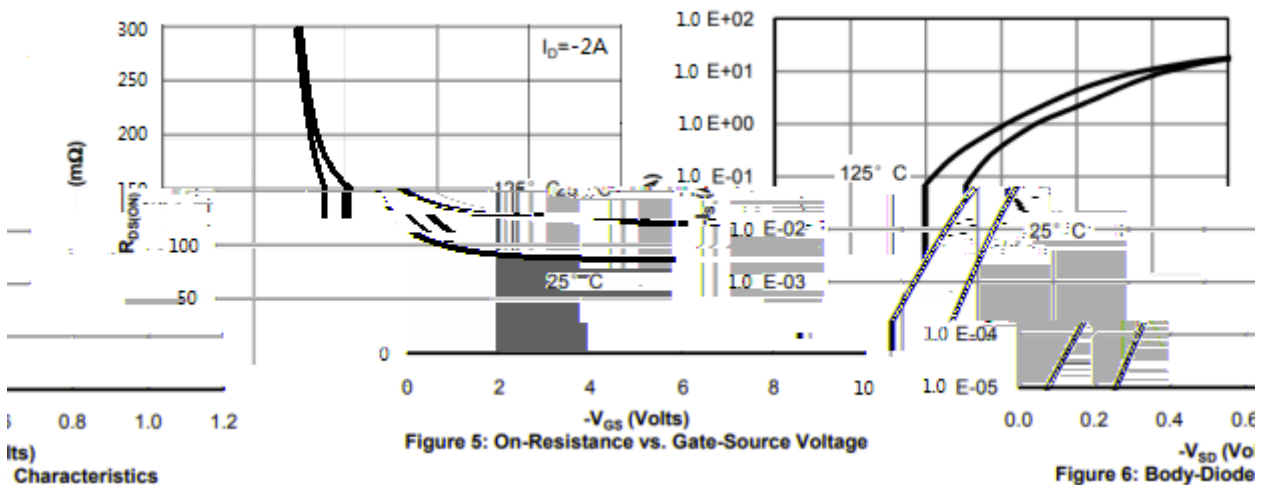
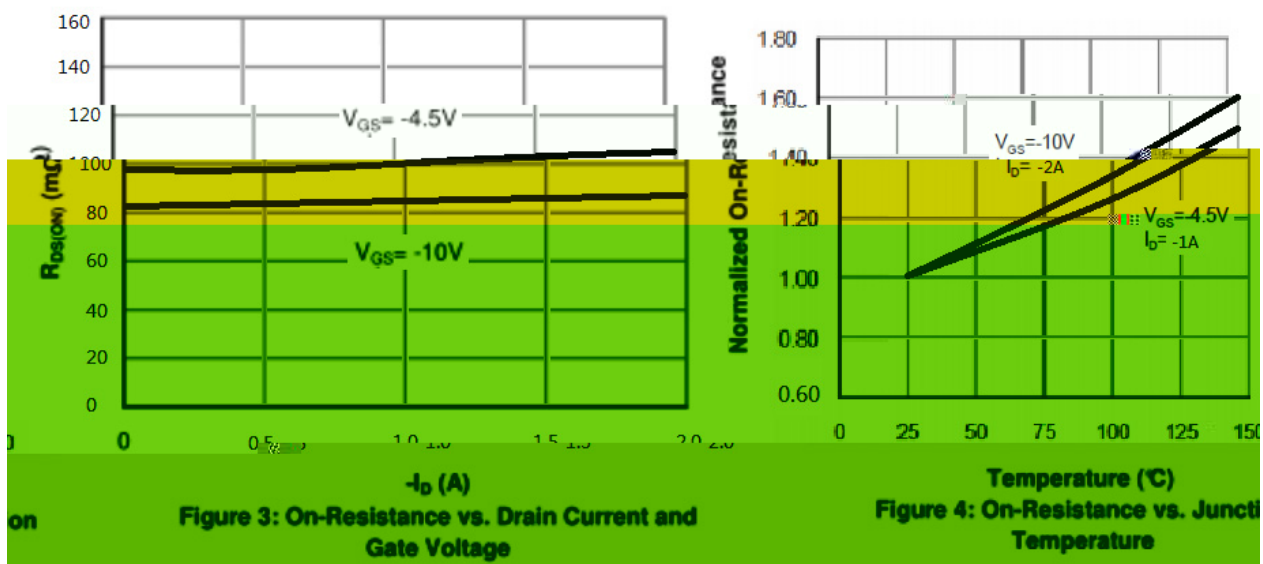
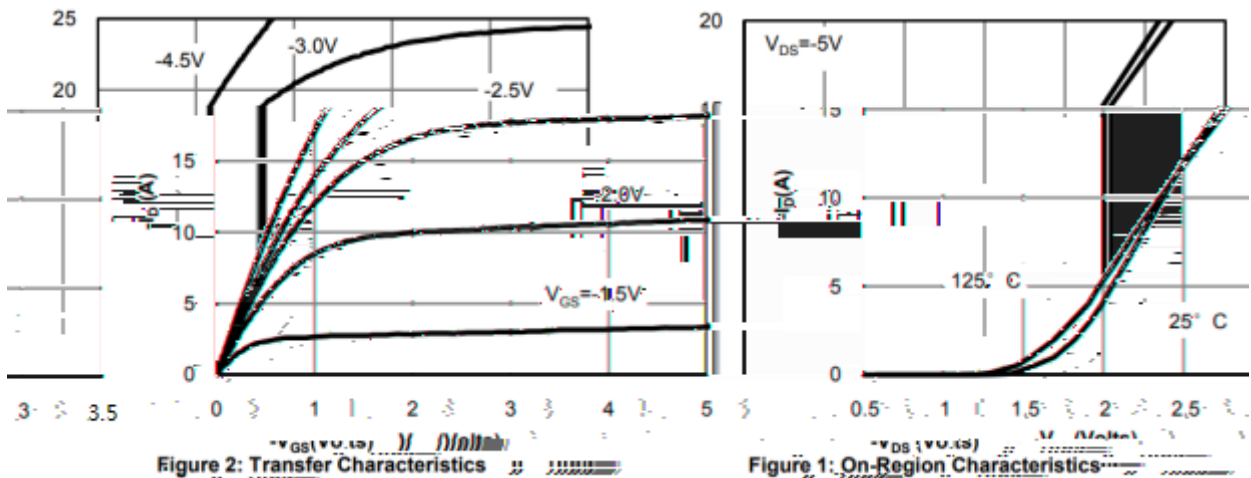
/ Absolute Maximum Ratings(Ta=25)

Parameter		Symbol	Rating	Unit
Drain–Source Voltage		V _{DSS}	-60	V
Gate–Body Leakage Voltage		V _{GSS}	±20	V
Drain Current - Continuous		I _D	-5	A
Power Dissipation (Surface Mounted on FR4 Board, t ≤ 10 sec.)		P _D	1.5	W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 150	°C
Maximum Junction-to-Ambient	t ≤ 10s	R _{θJA}	118.6	/W
Maximum Junction-to-Ambient	Steady-State		161.6	/W
Maximum Junction-to-Lead	Steady-State	R _{θJL}	83.3	/W

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-60	-63		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1	-1.5	-2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V$ $I_D=-2A$		84	100	m Ω
		$V_{GS}=-4.5V$ $I_D=-1A$		103	125	m Ω
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60V$ $V_{GS}=0V$			-1.0	μA
Gate-Body Leakage.	I_{GSS}	$V_{GS}=-20V$			-100	nA
		$V_{GS}=20V$			100	nA
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=-1A$ $T_J=25^{\circ}\text{C}$			-1.2	V
Input Capacitance	C_{iss}	$V_{DS}=-25V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		885		pF
Output Capacitance	C_{oss}			90		
Reverse Transfer Capacitance	C_{rss}			64		
Total Gate Charge	$Q_g(-10V)$	$V_{DS}=-30V$ $V_{GS}=-10.0V$ $I_D=-5A$		25		nC
Total Gate Charge	$Q_g(-4.5V)$			9.6		
Gate-to-Source Charge	Q_{gs}			3		
Gate-to-Drain Charge	Q_{gd}			7		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-30V$ $V_{GS}=-10V$ $R_L=7.5\Omega$ $R_G=3\Omega$		8		ns
Turn-On Rise Time	t_r			4		
Turn-Off Delay Time	$t_{d(off)}$			32		
Turn-Off Fall Time	t_f			7		

/ Electrical Characteristic Curve



/ Electrical Characteristic Curve

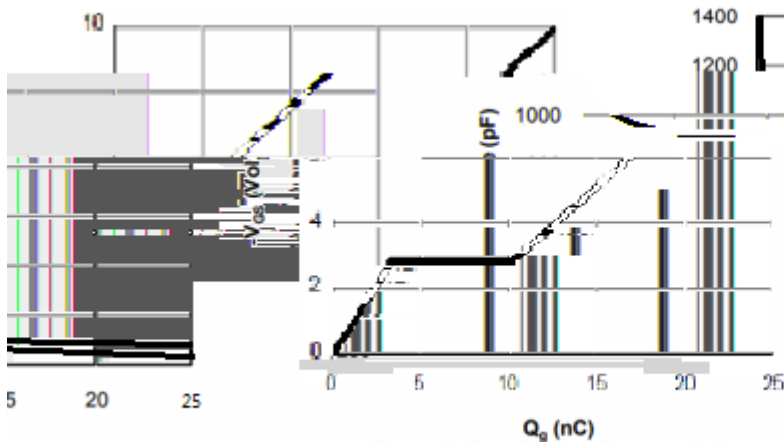


Figure 7: Gate-Charge Characteristics

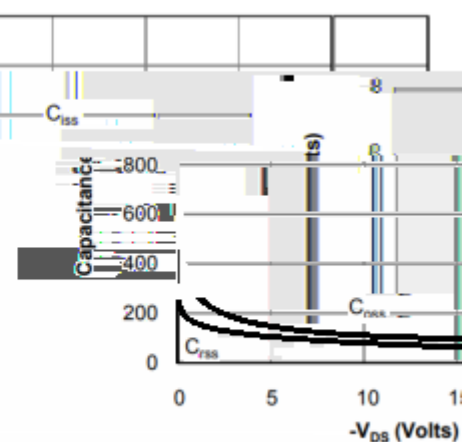


Figure 8: Capacitance Characteristics

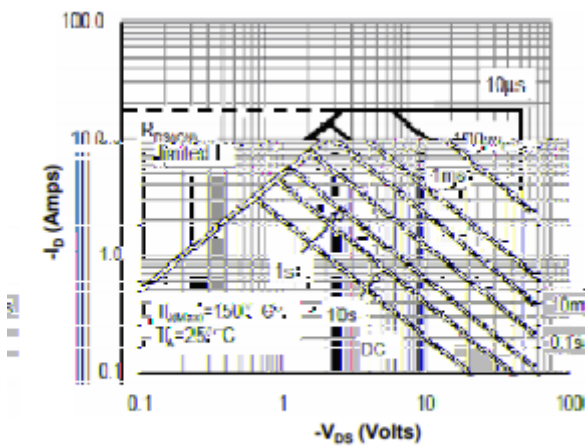


Figure 9: Maximum Forward Biased Safe Operating Area

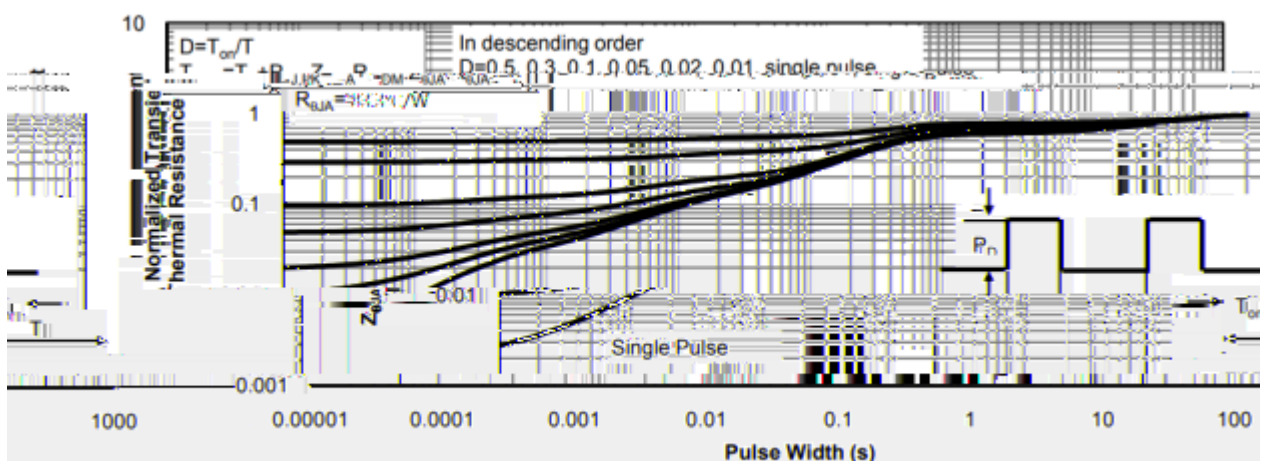
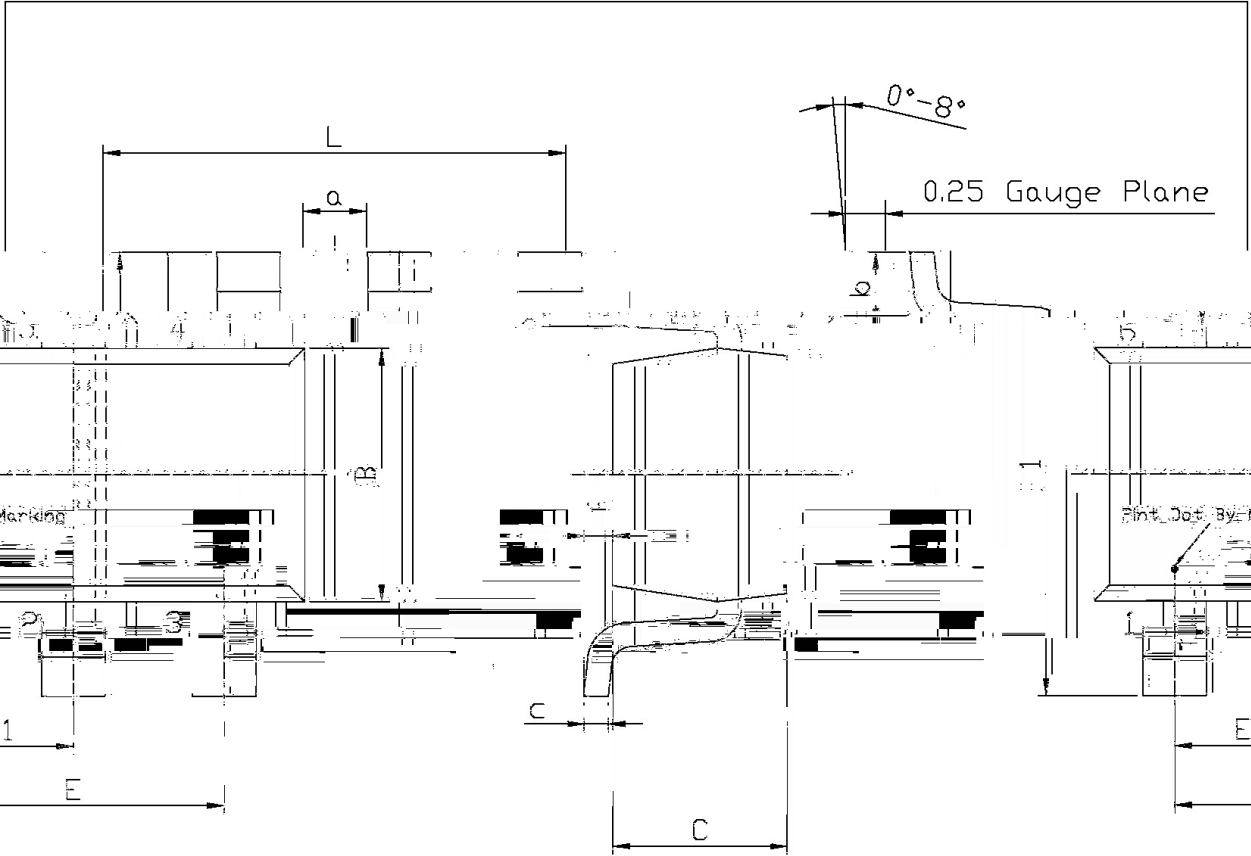


Figure 10: Normalized Maximum Transient Thermal Impedance

/ Package Dimensions

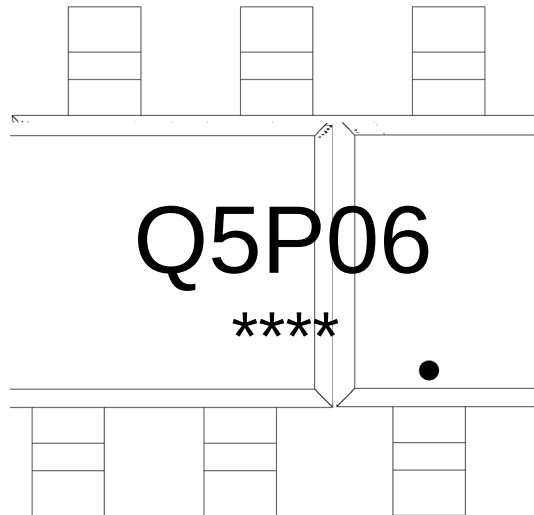


Unit: mm

Dimensions In Millimeters			Symbol	Dimensions In Millimeters		Symbol
Min	Max			Min	Max	
2.82	3.32		L	0.85	1.05	L
1.50	1.70		a	0.35	0.50	B
0.90	1.30		c	0.10	0.20	C
2.60	3.00		b	0.35	0.55	L1
1.80	2.00		F	0	0.15	E

SOT23-6

/ Marking Instructions



Q

5P06:

****:

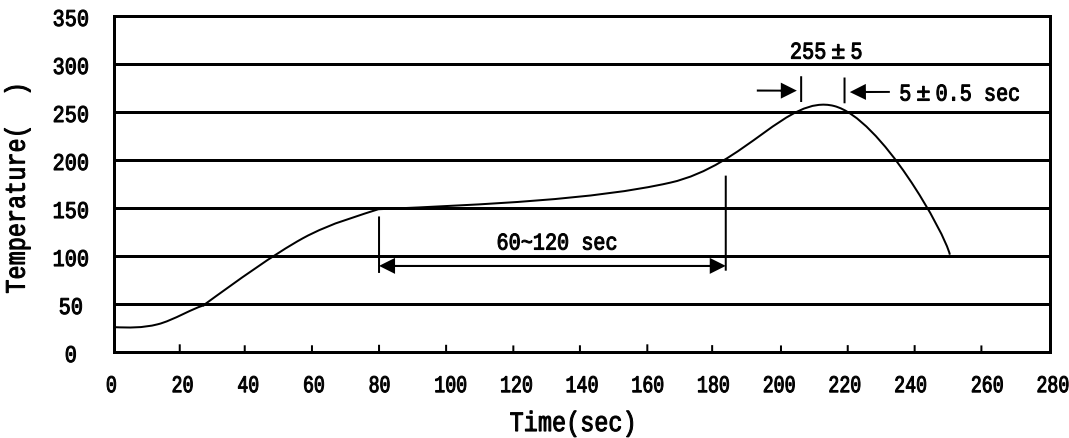
Note:

Q: Automobile halogen-free product Code

5P06 Product Type

****: Lot No. Code, code change with Lot No

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

150 200

60 120sec;

1.Preheating:150~200 , Time:60~120sec.
- 2

255±5

5±0.5sec;

2.Peak Temp.:255±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box
SOT23-5/6	3,000	10	30,000	4	120,000	7 ×8	210×205×205	445×230×435

/ Notices